

N-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY							
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A) ^a	Q _g (Typ.)				
30	0.022 at V _{GS} = 4.5 V	6.8	10 nC				
30	0.027 at V _{GS} = 2.5 V	6.0	TOTIC				

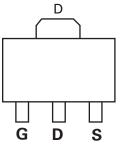
FEATURES

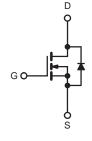
- Halogen-free
- TrenchFET[®] Power MOSFET

APPLICATIONS

· Load Switches for Portable Devices







N-Channel MOSFET

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V _{DS}	30	V	
Gate-Source Voltage	V _{GS}	± 20		
	$T_{\rm C} = 25 ^{\circ}{\rm C}$		6.8 ^a 6 ^a	
Continuous Drain Current (T _J = 150 °C)	T _C = 70 °C T _A = 25 °C	I _D	6.8 ^{a, b, c}	
	T _A = 70 °C		6 ^{a, b, c}	A
Pulsed Drain Current	I _{DM}	30		
Continuous Source-Drain Diode Current	T _C = 25 °C	I _S	5.2	
Continuous Cource Drain Diode Current	T _A = 25 °C	'5	2.1 ^{b, c}	
	T _C = 25 °C		6.3	
Maximum Power Dissipation	T _C = 70 °C	P _D	4	w
	T _A = 25 °C		2.5 ^{b, c}	vv
	T _A = 70 °C		1.6 ^{b, c}	
Operating Junction and Storage Temperatur	T _J , T _{stg}	- 55 to 150	℃	
Soldering Recommendations (Peak Temper	ature) ^{e, f}		260	U U

THERMAL RESISTANCE BATINGS

Parameter	Symbol Typical		Maximum	Unit					
Maximum Junction-to-Ambient ^{a, c, d}	t ≤ 5 s	R _{thJA}	40	50	°C/W				
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	15	20	0/11				

Notes:

a. Package limited, T_C = 25 °C.
b. Surface Mounted on 1" x 1" FR4 board.

c. t = 10 s.

d. Maximum under Steady State conditions is 95 °C/W.

e. See Reliability Manual for profile. The ChipFET is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

f. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

Symbol	rwise noted	Min	Turn	Max	Linit
Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Vee	$V_{re} = 0 V I_{re} = 250 \mu A$	20	1	1	V
	VGS = 0 V, ID = 200 µA	30	25		w mV/°C
	I _D = 250 μA				
. ,	$\lambda = \lambda = 250 \mu$	0.0	- 4.0	4.5	V
		0.6	-		
IGSS			-		nA
I _{DSS}					μA
				10	
I _{D(on)}	50 00	30			A
R _{DS(on})			0.022	0.033	Ω
00(01)			0.030	0.045	
9 _{fs}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 6.3 \text{ A}$		45		S
				1	
C _{iss}			1200		pF
C _{oss}	V_{DS} = 10 V, V_{GS} = 0 V, f = 1 MHz		220		
C _{rss}			100		
0	V_{DS} = 10 V, V_{GS} = 10 V, I_{D} = 6.3 A		22	33	nC
Qg			10	15	
Q _{gs}	$V_{\rm DS}$ = 10 V, $V_{\rm GS}$ = 4.5 V, $I_{\rm D}$ = 6.3 A		2.5		
Q _{gd}			1.7		
Rg	f = 1 MHz		2.4		Ω
t _{d(on)}			15	25	
t _r	V_{DD} = 10 V, R_L = 1.5 Ω		10	15	- ns
t _{d(off)}	$I_D \cong 6.7$ A, V_{GEN} = 4.5 V, R_g = 1 Ω		35	55	
t _f			12	20	
t _{d(on)}			10	15	
t _r	V_{DD} = 10 V, R _L = 1.5 Ω		12	20	
t _{d(off)}	$\text{I}_\text{D}\cong$ 6.7 A, V_GEN = 10 V, R_g = 1 Ω		25	40	
t _f			10	15	
s					I
۱ _S	T _C = 25 °C			5.2	A
I _{SM}				30	
	$I_{S} = 6.7 \text{ A}, V_{GS} = 0 \text{ V}$		0.8	1.2	V
			20	40	ns
				20	nC
	I _F = 6.7 A, dl/dt = 100 A/μs, T _J = 25 °C			-	ns
t _b			10		
	$ D(on) $ $R_{DS(on)}$ g_{fs} C_{iss} C_{oss} C_{rss} Q_{g} Q_{gd} R_{g} $t_{d(on)}$ t_{r} $t_{d(off)}$ t_{f} $t_{d(off)}$ t_{f} $t_{d(off)}$ t_{r}	$\begin{tabular}{ c c c c } \hline V_{DS} & V_{GS} = 0 \ V, \ I_{D} = 250 \ \mu A \\ \hline \Delta V_{DS} \ / T_{J} & I_{D} = 250 \ \mu A \\ \hline \Delta V_{GS(th)} & V_{DS} = V_{GS} \ , \ I_{D} = 250 \ \mu A \\ \hline I_{GSS} & V_{DS} = 0 \ V, \ V_{GS} = \pm 20 \ V \\ \hline V_{DS} = 30 \ V, \ V_{GS} = 0 \ V \\ \hline V_{DS} = 30 \ V, \ V_{GS} = 0 \ V \\ \hline V_{DS} = 30 \ V, \ V_{GS} = 0 \ V \\ \hline V_{DS} = 30 \ V, \ V_{GS} = 0 \ V \\ \hline V_{DS} = 30 \ V, \ V_{GS} = 0 \ V \\ \hline V_{DS} = 30 \ V, \ V_{GS} = 0 \ V \\ \hline V_{DS} = 5 \ V, \ V_{GS} = 4.5 \ V \\ \hline V_{DS} = 10 \ V, \ V_{DS} = 10 \ V, \ I_{D} = 6.3 \ A \\ \hline V_{DS} = 10 \ V, \ V_{GS} = 10 \ V, \ I_{D} = 6.3 \ A \\ \hline V_{DS} = 10 \ V, \ V_{GS} = 10 \ V, \ I_{D} = 6.3 \ A \\ \hline Q_{gd} & V_{DS} = 10 \ V, \ V_{GS} = 10 \ V, \ I_{D} = 6.3 \ A \\ \hline Q_{gd} & V_{DS} = 10 \ V, \ V_{GS} = 4.5 \ V, \ I_{D} = 6.3 \ A \\ \hline Q_{gd} & V_{DS} = 10 \ V, \ V_{GS} = 4.5 \ V, \ I_{D} = 6.3 \ A \\ \hline Q_{gd} & I_{D} = 6.7 \ A, \ V_{GEN} = 4.5 \ V, \ I_{D} = 6.3 \ A \\ \hline Q_{DD} = 10 \ V, \ R_{L} = 1.5 \ \Omega \\ \hline I_{d} = 6.7 \ A, \ V_{GEN} = 10 \ V, \ R_{g} = 1 \ \Omega \\ \hline I_{T} & V_{DD} = 10 \ V, \ R_{L} = 1.5 \ \Omega \\ \hline I_{D} = 6.7 \ A, \ V_{GEN} = 10 \ V, \ R_{g} = 1 \ \Omega \\ \hline T_{f} & V_{DD} = 10 \ V, \ R_{L} = 1.5 \ \Omega \\ \hline I_{D} = 6.7 \ A, \ V_{GEN} = 10 \ V, \ R_{g} = 1 \ \Omega \\ \hline T_{f} & I_{D} = 6.7 \ A, \ V_{GEN} = 10 \ V, \ R_{g} = 1 \ \Omega \\ \hline T_{f} & I_{D} = 6.7 \ A, \ V_{GEN} = 10 \ V, \ R_{g} = 1 \ \Omega \\ \hline T_{f} & I_{F} = 6.7 \ A, \ V_{GS} = 0 \ V \\ \hline T_{fr} & V_{SD} & I_{S} = 6.7 \ A, \ V_{GS} = 0 \ V \\ \hline T_{fr} & V_{SD} & I_{S} = 6.7 \ A, \ V_{GS} = 0 \ V \\ \hline T_{fr} & V_{SD} & I_{S} = 6.7 \ A, \ V_{GS} = 0 \ V \\ \hline T_{fr} & V_{SD} & I_{S} = 6.7 \ A, \ V_{GS} = 0 \ V \\ \hline T_{fr} & V_{SD} & I_{S} = 6.7 \ A, \ V_{GS} = 0 \ V \\ \hline T_{fr} & V_{SD} & I_{S} = 6.7 \ A, \ V_{GS} = 0 \ V \\ \hline T_{fr} & V_{SD} & I_{S} = 6.7 \ A, \ V_{GS} = 0 \ V \\ \hline T_{fr} & V_{SD} & I_{S} = 6.7 \ A, \ V_{GS} = 0 \ V \\ \hline T_{fr} & V_{SD} & I_{S} = 6.7 \ A, \ V_{SD} = 0 \ V \\ \hline T_{fr} & V_{SD} & I_{S} = 6.7 \ A, \ V_{SD} = 0 \ V \\ \hline T_{fr} & V_{SD} & I_{S} = 6.7 \ A, \ V_{SD} = 0 \ V \\ \hline T_{fr$	$\begin{tabular}{ c c c c } \hline V_{DS} & V_{GS} = 0 \ V, \ I_{D} = 250 \ \mu A & 30 \\ \hline \Delta V_{DS}/T_J & I_D = 250 \ \mu A & 0.6 \\ \hline I_{QS} & V_{DS} = V_{GS}, \ I_D = 250 \ \mu A & 0.6 \\ \hline I_{QSS} & V_{DS} = 0 \ V, \ V_{QS} = 120 \ V & V_{DS} = 30 \ V, \ V_{QS} = 0 \ V & V_{DS} = 30 \ V, \ V_{QS} = 0 \ V & V_{DS} = 30 \ V, \ V_{GS} = 0 \ V & V_{DS} = 30 \ V, \ V_{GS} = 4.5 \ V & 30 \\ \hline V_{DS} = 30 \ V, \ V_{GS} = 4.5 \ V & 30 \\ \hline V_{DS} = 10 \ V, \ V_{DS} = 10 \ V, \ I_D = 6.3 \ A & V_{DS} = 10 \ V, \ I_D = 6.3 \ A & V_{DS} = 10 \ V, \ V_{DS} = 10 \ V, \ I_D = 6.3 \ A & V_{DS} = 10 \ V, \ V_{DS} = 10 \ V, \ I_D = 6.3 \ A & V_{DS} = 10 \ V, \ V_{DS} = 10 \ V, \ I_D = 6.3 \ A & V_{DS} = 10 \ V, \ I_D = 6.3 \ A & V_{DS} = 10 \ V, \ V_{DS} = 10 \ V, \ I_D = 6.3 \ A & V_{DS} = 10 \ V, \ I_D = 6.3 \ A & V_{DS} = 10 \ V, \ I_D = 6.3 \ A & V_{DS} = 10 \ V, \ I_D = 6.3 \ A & V_{DS} = 10 \ V, \ I_D = 6.3 \ A & V_{DS} = 10 \ V, \ I_D = 6.3 \ A & V_{DS} = 10 \ V, \ I_D = 6.3 \ A & V_{DS} = 10 \ V, \ I_D = 6.3 \ A & V_{DS} = 10 \ V, \ V_{DS} = 10 \ V, \ I_D = 6.3 \ A & V_{DS} = 10 \ V, \ I_D = 6.3 \ A & V_{DS} = 10 \ V, \ I_D = 6.3 \ A & V_{DS} = 10 \ V, \ I_D = 6.3 \ A & V_{DS} = 10 \ V, \ I_D = 6.3 \ A & V_{DS} = 10 \ V, \ I_D = 6.3 \ A & V_{DS} = 10 \ V, \ I_D = 6.3 \ A & V_{DS} = 10 \ V, \ I_D = 6.3 \ A & V_{DS} = 10 \ V, \ I_D = 10 \ V, $	$\begin{tabular}{ c c c c c } \hline V_{DS} & V_{GS} = 0 \ V, \ I_D = 250 \ \mu A & 30 & 25 \\ \hline \Delta V_{DS}/T_J & I_D = 250 \ \mu A & -4.0 & 25 \\ \hline \Delta V_{GS}(th) & V_{DS} = V_{GS}, \ I_D = 250 \ \mu A & 0.6 & -4.0 & -4.$	$\begin{array}{c c c c c c c c c c c c c c c c c c c $

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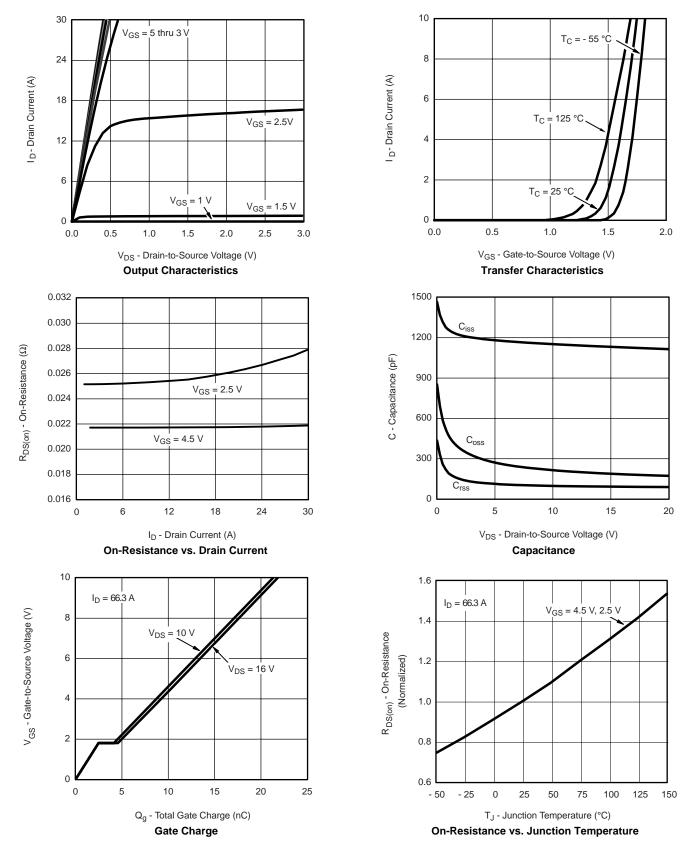
a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing.

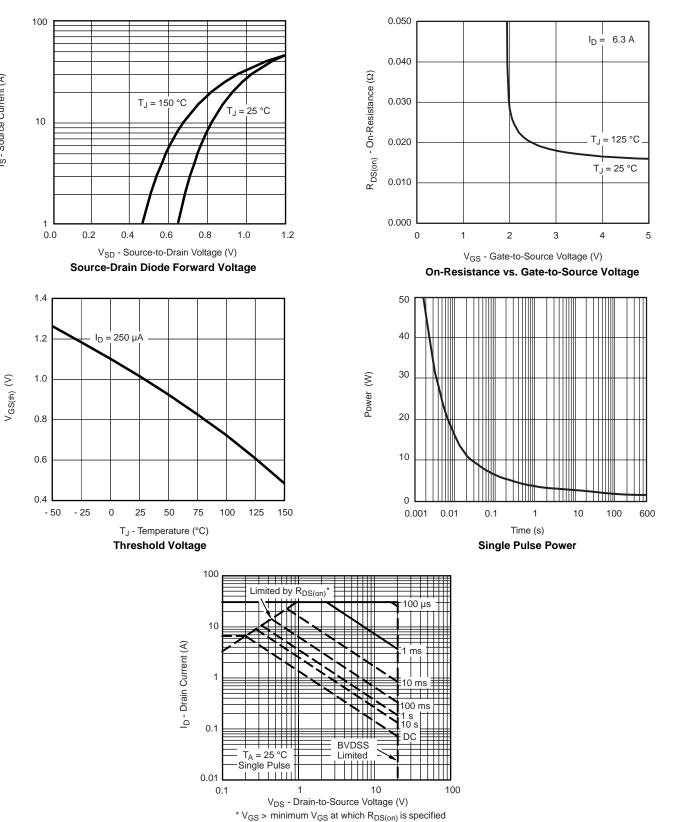
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Is - Source Current (A)



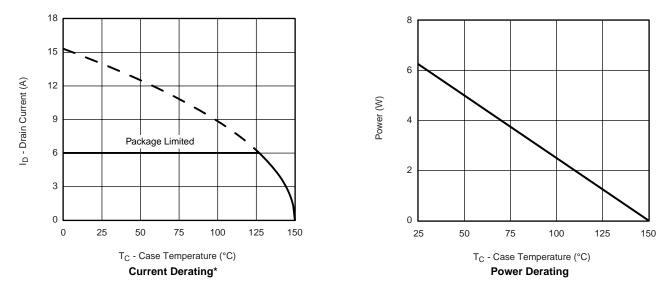
Safe Operating Area, Junction-to-Ambient

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



* The power dissipation P_D is based on $T_{J(max)}$ = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

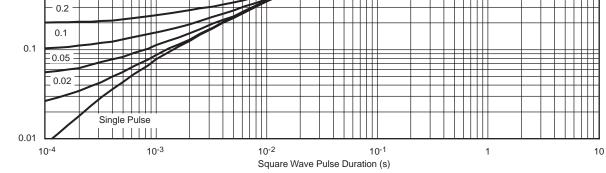
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2 1 Duty Cycle = 0.5 + + + + + + 0.2 \mathbb{H} Notes: 0.1 4 P_{DM} 0.1 0.05 t₁ t₂ ++ t₁ 0.02 1. Duty Cycle, D = t2 2. Per Unit Base = RthJA 80 °C/W 3. $T_{JM} - T_A = P_{DM}Z_{thJA}^{(t)}$ Single Pulse 4. Surface Mounted 0.01 10⁻³ 10-4 10⁻² 10-1 10 100 600 1 Square Wave Pulse Duration (s) Normalized Thermal Transient Impedance, Junction-to-Ambient 2 1 Duty Cycle = 0.5 Normalized Effective Transient Thermal Impedance \square 0.2 0.1 0.1 0.05 0.02

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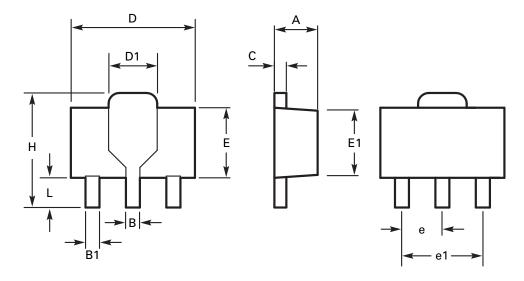
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot



Package outline - SOT89



DIM	Millim	neters	Inc	hes	DIM	Millimeters		Inches	
	Min	Max	Min	Max		Min	Max	Min	Max
А	1.40	1.60	0.550	0.630	E	2.29	2.60	0.090	0.102
В	0.44	0.56	0.017	0.022	E1	2.13	2.29	0.084	0.090
B1	0.36	0.48	0.014	0.019	е	1.50 BSC		0.059 BSC	
С	0.35	0.44	0.014	0.017	e1	3.00 BSC		0.118 BSC	
D	4.40	4.60	0.173	0.181	Н	3.94	4.25	0.155	0.167
D1	1.62	1.83	0.064	0.072	L	0.89	1.20	0.035	0.047

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches



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